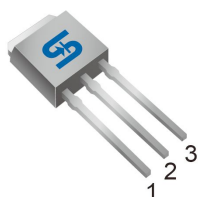
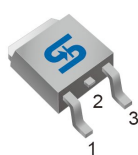


TO-251
(IPAK)



TO-252
(DPAK)



Pin Definition:

1. Base
2. Collector
3. Emitter

PRODUCT SUMMARY

BV_{CEO}	400V
BV_{CBO}	700V
I_C	3A
$V_{CE(SAT)}$	0.17V @ $I_C=1A, I_B=0.25A$

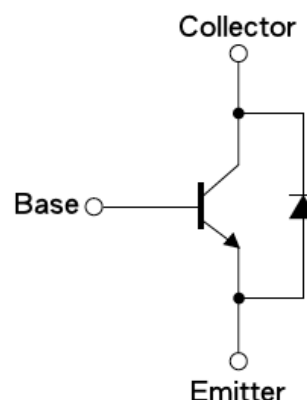
Features

- Build-in Free-wheeling Diode Makes Efficient Anti-saturation Operation
- No Need to Interest an h_{FE} Value Because of Low Variable Storage-time Spread Even Though Corner Spirit Product.
- Low Base Drive Requirement
- Suitable for Half Bridge Light Ballast Application

Structure

- Silicon Triple Diffused Type
- NPN Silicon Transistor
- Integrated Anti-parallel Collector-Emitter Diode

Block Diagram



Ordering Information

Part No.	Package	Packing
TSC5303DCP ROG	TO-252	2.5kpcs / 13" Reel
TSC5303DCH C5G	TO-251	75pcs / Tube

Note: "G" denotes Halogen Free Products

Absolute Maximum Ratings (Ta = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	700	V
Collector-Emitter Voltage @ $V_{BE}=0V$	V_{CES}	700	V
Collector-Emitter Voltage	V_{CEO}	400	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current	I_C	3	A
Collector Peak Current (tp < 5ms)	I_{CM}	6	A
Base Current	I_B	1.5	A
Base Peak Current (tp < 5ms)	I_{BM}	3	A
Power Total Dissipation @ $T_C=25^\circ C$	P_{DTOT}	30	W
Maximum Operating Junction Temperature	T_J	+150	°C
Storage Temperature Range	T_{STG}	-55 to +150	°C

Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Case	$R\theta_{JC}$	4.15	$^{\circ}\text{C/W}$
Thermal Resistance - Junction to Ambient	$R\theta_{JA}$	75	$^{\circ}\text{C/W}$

Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Static						
Collector-Base Voltage	$I_C = 1\text{mA}, I_B = 0$	BV_{CBO}	700	--	--	V
Collector-Emitter Breakdown Voltage	$I_C = 10\text{mA}, I_E = 0$	BV_{CEO}	400	--	--	V
Emitter-Base Breakdown Voltage	$I_E = 1\text{mA}, I_C = 0$	BV_{EBO}	9	--	--	V
Collector Cutoff Current	$V_{CB} = 700\text{V}, I_E = 0$	I_{CBO}	--	--	10	μA
Collector Cutoff Current	$V_{CE} = 400\text{V}, I_B = 0$	I_{CEO}	--	--	10	μA
Emitter Cutoff Current	$V_{EB} = 7\text{V}, I_C = 0$	I_{EBO}	--	--	10	μA
Collector-Emitter Saturation Voltage	$I_C = 0.4\text{A}, I_B = 0.1\text{A}$	$V_{CE(SAT)1}$	--	0.10	0.7	V
	$I_C = 1\text{A}, I_B = 0.25\text{A}$	$V_{CE(SAT)2}$	--	0.17	1	
	$I_C = 2\text{A}, I_B = 0.5\text{A}$	$V_{CE(SAT)3}$	--	0.55	--	
Base-Emitter Saturation Voltage	$I_C = 1\text{A}, I_B = 0.25\text{A}$	$V_{BE(SAT)1}$	--	--	1.1	V
	$I_C = 2\text{A}, I_B = 0.5\text{A}$	$V_{BE(SAT)2}$	--	--	1.2	
DC Current Gain	$V_{CE} = 5\text{V}, I_C = 10\text{mA}$	h_{FE}	10	--	--	
	$V_{CE} = 5\text{V}, I_C = 1\text{A}$		15	--	30	
	$V_{CE} = 5\text{V}, I_C = 2\text{A}$		5	--	--	
Forward Voltage Drop	$I_F = 2\text{A}$	V_f	--	--	2	V
Turn On Time	$V_{CC} = 250\text{V}, I_C = 1\text{A},$	t_{ON}	--	0.2	0.6	μs
Storage Time	$I_{B1} = I_{B2} = 0.2\text{A}, t_p = 25\mu\text{s}$	t_{STG}	--	2.7	4.5	μs
Fall Time	Duty Cycle < 1%	t_f	--	0.16	0.3	μs

Note: Pulsed duration = 380 μs , duty cycle $\leq 2\%$

Electrical Characteristics Curve ($T_a = 25^\circ\text{C}$, unless otherwise noted)

Figure 1. Static Characteristics

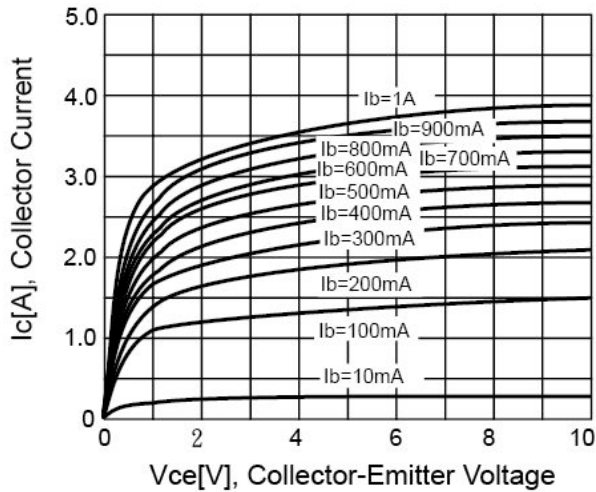


Figure 2. DC Current Gain

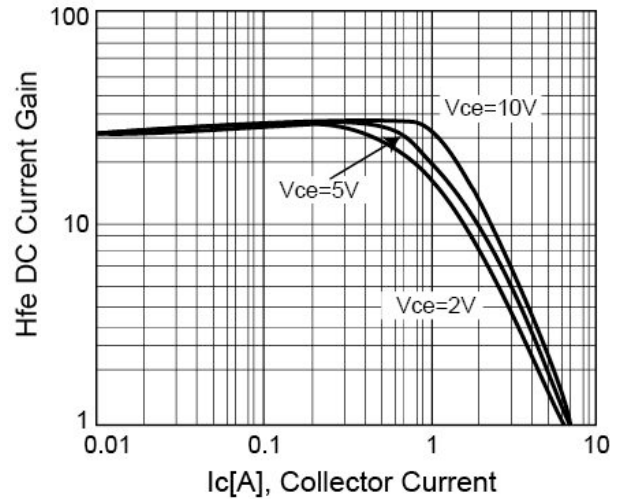


Figure 3. $V_{ce(sat)}$ v.s. $V_{be(sat)}$

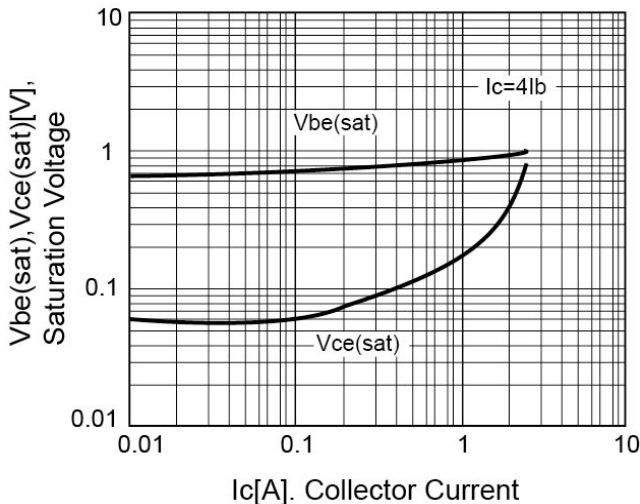


Figure 4. Power Derating

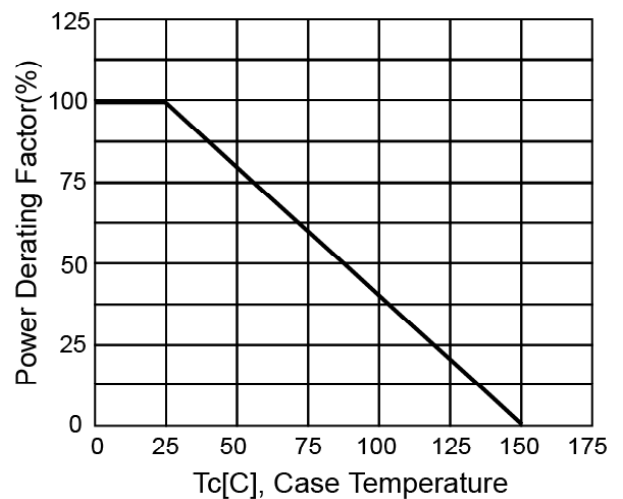


Figure 5. Reverse Bias SOA

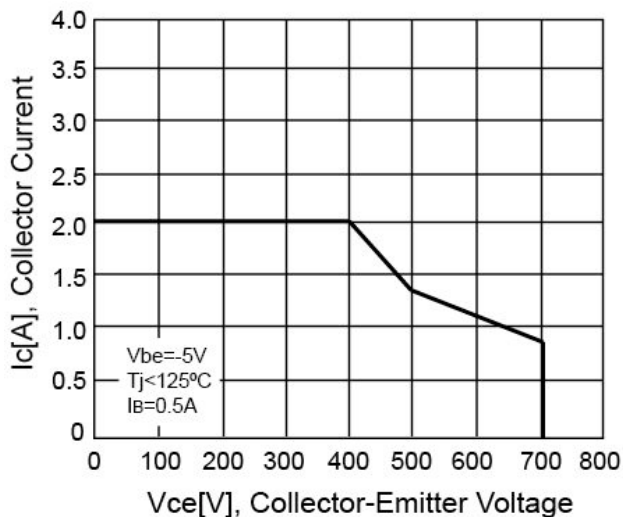
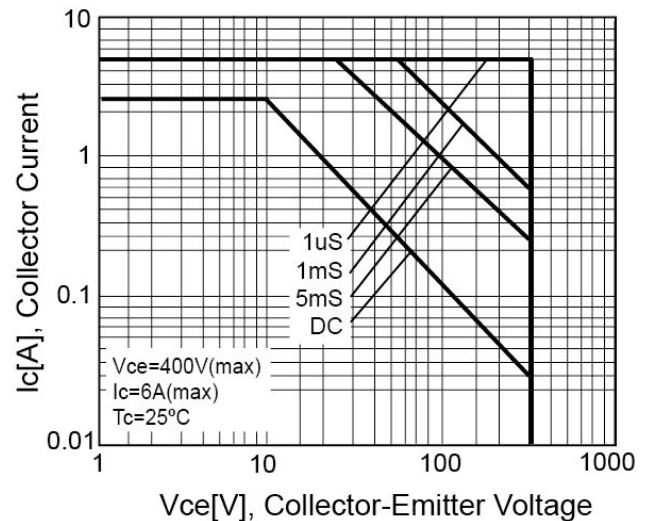
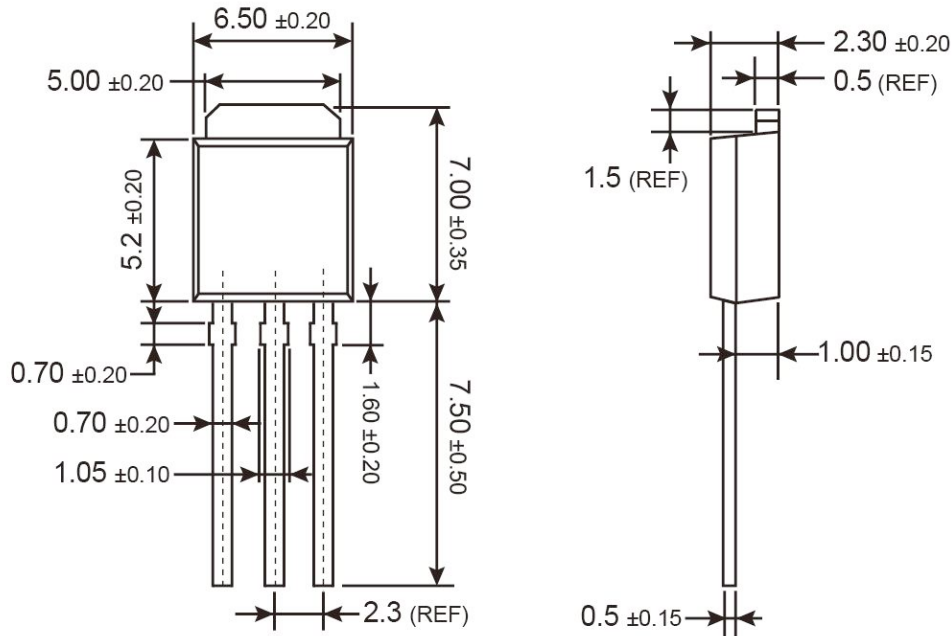


Figure 6. Safety Operating Area

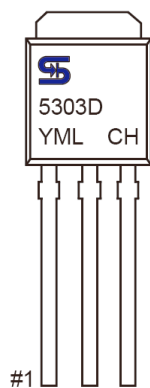


TO-251 Mechanical Drawing



Unit: Millimeters

Marking Diagram



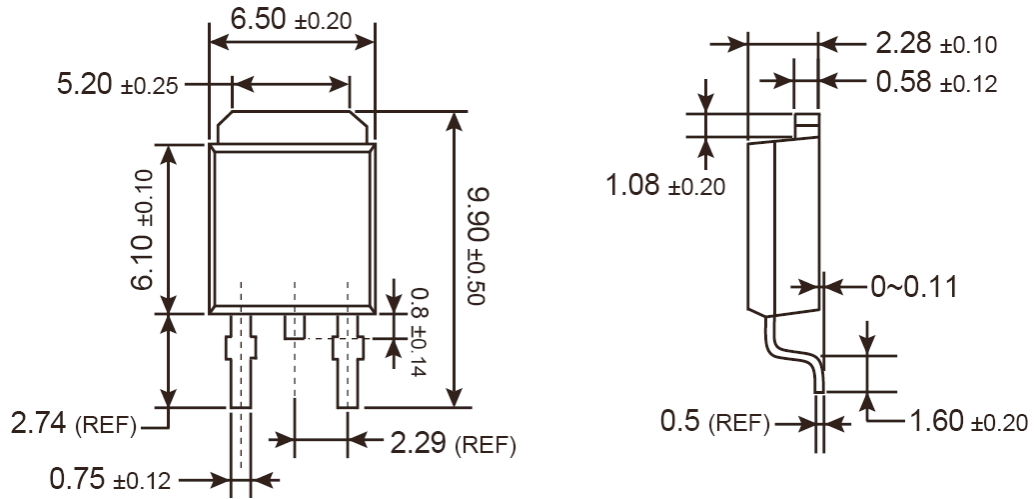
Y = Year Code

M = Month Code for Halogen Free Product

(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)

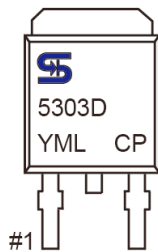
L = Lot Code

TO-252 Mechanical Drawing



Unit: Millimeters

Marking Diagram



- Y** = Year Code
- M** = Month Code for Halogen Free Product
(**O**=Jan, **P**=Feb, **Q**=Mar, **R**=Apr, **S**=May, **T**=Jun, **U**=Jul, **V**=Aug, **W**=Sep, **X**=Oct, **Y**=Nov, **Z**=Dec)
- L** = Lot Code

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